Article

Influence of Sputtering Power of ZrB$_2$ Target on Structure and Properties of Nanocomposite Zr-B-O Films

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Abstract: The nanocomposite Zr-B-O films based on ZrB$_2$ and ZrO$_2$ are successfully deposited on Si (100) and stainless-steel substrates via a multi-target magnetron co-sputtering system. The influence of the sputtering power of ZrB$_2$ target on sample structure and performance was analyzed by scanning electron microscope (SEM), transmission electron microscope (TEM), X-ray diffraction (XRD), and X-ray photoelectron spectrometer (XPS). Nano scratch tests were conducted to measure the films’ mechanical properties. Their oxidation resistance in an aerobic environment was tested by high-temperature oxidation in a muffle furnace. Corrosion behaviors of the Zr-B-O films were evaluated by potentiodynamic polarization and electrochemical impedance spectroscopy. It shows that the interior of the composite films has a high degree of non-crystallization. The maximum hardness (26.76 GPa) and corresponding elastic modulus (268.05 GPa) of the film were obtained at the sputtering power of 120 W. The hardest film also shows the better oxidation resistance with a mass change of around 0.1% before and after oxidation under 1000 $^\circ$C for 1 h. However, the corrosion resistance of Zr-B-O nanocomposite films is negatively correlated with the power of ZrB$_2$, which is related to the microstructure of the composite film.

Keywords: Zr-B-O nanocomposite films; magnetron co-sputtering; sputtering power; hardness; oxidation resistance; corrosion resistance

1. Introduction

In recent years, there are increasingly higher requirements for materials used in engineering components, processing tools, and other application fields, especially on mechanical properties, friction and wear properties, high-temperature resistance, and corrosion resistance [1,2]. As the protective coating of tools, hard nanocomposite films need to be modified to improve their comprehensive performances, which can extend the service life of tools in industrial applications and prevent rapid failure in extreme harsh environments [3–9]. ZrB$_2$, as a typical of transition metal diboride, has a simple hexagonal crystal structure. Its inherent crystal structure and firm combination of B–B covalent bonds determine that ZrB$_2$ has good chemical stability and excellent physical properties, including high elastic modulus, high hardness, and a moderate thermal expansion coefficient [10,11]. However, the high concentration of B–B covalent bonds and the low self-diffusion coefficient of ZrB$_2$ leads to the decrease of compactness [12]. In addition, ZrB$_2$ has the drawbacks of low fracture toughness, low mechanical reliability, and unreliable high-temperature properties, which also need to be improved for better application [13–15].

Different from boride, ZrO$_2$ is a kind of high-temperature resistant material. Due to its good thermal stability, high-temperature strength, and corrosion resistance, ZrO$_2$ has been widely used
for nanomaterials, multilayer composite materials, and microelectronic materials [16–18]. However, pure ZrO$_2$ needs to be stabilized by introducing other materials, because the volume of ZrO$_2$ will change due to the phase transition. It is hopeful that high mechanical strength, excellent oxidation resistance, and good corrosion resistance can all be obtained by doping oxide to boride. Many studies have already combined them with other materials to prepare composite materials with better properties by the hot-pressing method [19–24]. The hot-pressing method can easily make the material phase change, leading to an increase of porosity and grain size. The magnetron sputtering method can make up the defects caused by phase transition, and the prepared films are usually uniform, dense, and have good adhesion to the substrate. Therefore, the nanocomposite films with the desired structure and performance can be produced by directly mixing ZrB$_2$ and ZrO$_2$ using the magnetron co-sputtering method.

In this work, the Zr-B-O nanocomposite films are deposited on Si (100) and stainless-steel substrate by sputtering ZrB$_2$ and ZrO$_2$ targets using multi-target magnetron co-sputtering. This method can accurately control deposition parameters and realize the combination of ZrB$_2$ and ZrO$_2$ at low temperature. As the ZrO$_2$ target is more fragile than the ZrB$_2$ target, we choose to change the sputtering power of ZrB$_2$ target to control the deposition rate so as to obtain the films with a different thickness and composition. The main purpose of this work is to investigate the effect of the sputtering power of the ZrB$_2$ target on the microstructure, mechanical properties, oxidation resistance, and corrosion resistance of Zr-B-O films. Thus, an optimum composition is expected to yield superior comprehensive properties.

2. Materials and Methods

Zr-B-O nanocomposite films at different sputtering power of ZrB$_2$ were deposited by a computer-controlled magnetron sputtering system. High purity targets of ZrB$_2$ (99.99%, diameter 50.8 mm, thickness 4 mm, HZAM, Beijing, China) and ZrO$_2$ (99.99%, diameter 50.8 mm, thickness 4 mm, HZAM, Beijing, China) were respectively connected to direct current-pulsed (DC) and radio frequency (RF) source sputter guns, which were fixed at both sides of chamber. The heated sample holder which was 7 cm away from the two co-sputtering targets was placed on the top of the chamber. Its rotation speed was 1 r/min. Silicon wafers (100) and stainless-steel substrates were cleaned in an ultrasonic agitator in acetone (99.7%) and ethanol (99.7%) ordinally for 15 min and then dried using compressed air before being mounted on a rotatable substrate holder. The chamber was first vacuumed to a base pressure lower than $4.5 \times 10^{-4}$ Pa, and then the high purity argon (99.999%) plasma was introduced into the chamber to clean substrates for 15 min at $-350$ V bias voltages and a pressure of 5.0 Pa prior to the deposition of nanocomposite films. Impurities and adsorbed gases on the surface of substrates were removed by low bias voltage. The preparation of Zr-B-O nanocomposite films was carried out under a work pressure of 0.4 Pa and an Ar gas flow of 40 sccm. The ZrO$_2$ target was deposited at a fixed power of 80 W, while the ZrB$_2$ target was deposited at different powers from 80 to 120 W at room temperature with $-80$ V bias voltage. The deposition time was 3 h, and the final thickness of the films was about 600–800 nm. The experimental schematic diagram of this study is shown in Figure 1.

A scanning electron microscope (SEM, SU8010, Hitachi, Tokyo, Japan) was used to survey the thickness and the fracture surface morphology of the Zr-B-O film. Meanwhile, the sectioned surface morphology of the nanocomposite films was observed by a high-resolution transmission electron microscope (HRTEM, JEM-2100F, JEOL, Tokyo, Japan). Wide angle X-ray diffraction (XRD, D8A, Bruker, Karlsruhe, Germany) with Cu-K$_\alpha$ (40 kV, 20 mA, $\lambda = 1.54056$ Å) radiation was used to determine the films’ microstructure and crystalline nature. An X-ray photoelectron spectrometer (XPS, PHI5000VersaProbe, Ulvac-Phi, Chigasaki, Japan) was used to characterize the chemical composition and chemical bonds. The contaminated C$_{1s}$ (284.6 eV) was used as a reference for correcting charge shift. Furthermore, these XPS spectra were fitted by XPSPEAK software (version 4.1), and Shirley background was chosen for background calculation of these XPS spectra.
where $\Delta M$ is the mass change, $M$ is the mass after annealing (in grams) and $M_0$ is the mass before heating of samples, respectively.

Electrochemical impedance spectroscopy (EIS) and potentiodynamic polarization were measured by an electrochemical workstation (PARSTAT 2273, Princeton Applied Research, San Diego, CA, USA) at room temperature in a 3.5 wt.% NaCl aqueous solution, and the corrosion behavior of the samples was evaluated. A classical three electrode system was carried out, in which samples with stainless-steel substrates were used as the working electrode (exposed area 1 cm$^2$), a platinum net and a saturated calomel electrode (SCE) served as auxiliary electrode and reference electrode, respectively. EIS experiments were conducted at open circuit potential with an AC amplitude of 0.01 V and a frequency range of 0.1 MHz to 0.01 Hz. Potentiodynamic polarization experiments were operated at a scan rate of 0.01 V/s.

3. Results and Discussion

3.1. Microstructures and Mechanical Properties

Figure 2a shows a fractured cross-sectional SEM image of the Zr-B-O nanocomposite film deposited at 80 W sputtering power of ZrB$_2$ at room temperature. Apparently, the Zr-B-O nanocomposite film was successfully synthesized on Si (100) substrate. As can be seen from the image, the nanocomposite film shows a fine-grained microstructure character for magnetron sputtered boride film [27]. The thickness of the film with 80 W power of ZrB$_2$ is approximately 600 nm resulting from a deposition rate of about 3.85 nm·min$^{-1}$. In addition, it should be noted that during the deposition process, high-energy particles, and energetic ions bombard the newly formed film, leading to the attenuation of
film thickness [28]. In order to remove the influence of different film thicknesses on the experimental results, we keep the thickness of Zr-B-O nanocomposite films at 600–800 nm under different sputtering powers of ZrB$_2$ target. Simultaneously, top view SEM images of ZrO$_2$, ZrB$_2$, and Zr-B-O films were compared in Figure 2b–d. It can be clearly seen that these films prepared by magnetron co-sputtering have smooth surfaces, fewer defects, and good compactness. It would be more conducive to deterring outside destruction.

![Cross-sectional SEM image of Zr-B-O film](image)

Figure 2. Cross-sectional SEM image of (a) nanocomposite Zr-B-O film and top view SEM images of (b) ZrO$_2$, (c) ZrB$_2$, and (d) Zr-B-O films.

The X-ray diffraction patterns of a monolayer ZrB$_2$ film and a monolayer ZrO$_2$ film deposited on Si (100) substrates are shown in Figure 3a. The ZrB$_2$ and ZrO$_2$ targets were respectively sputtered in DC mode and RF mode with the power of 80 W during the deposition process. Clearly, the ZrB$_2$ monolayer has a main peak at (001) and a sub-peak at (101). This indicates that the sample has a hexagonal symmetrical structure with alternating Zr and B atomic layers. ZrO$_2$ exhibits the low-temperature monoclinic phase, and appears mixed orientation at (200) and (002) diffraction peaks. Figure 3b depicts the XRD diffractograms of Zr-B-O nanocomposite films with different powers of ZrB$_2$. With the power increasing from 80 to 120 W, no obvious diffraction peak corresponding to (001) and (101) crystal plane of ZrB$_2$ is found. Meanwhile, the (111) crystal orientation of monoclinic ZrO$_2$ at about 31° is not obvious. These samples are almost in an amorphous state and some sub-crystals are formed inside, which causes the films densification in the interface. Compared with monolayer films, sputtering two targets simultaneously can inhibit their crystallinities to some extent. Because the two stages of atom collision cascade and rapid relaxation in the coating process will cause the loss of energy, which is conducive to the formation of amorphous structure, as illustrated in Figure 1 [29].

Figure 4a exhibits high-resolution XPS spectra of Zr$_{3d}$ for the Zr-B-O nanocomposite films at 80 W sputtering power of ZrB$_2$ target. The narrow spectrum of Zr$_{3d}$ is split into two strong peaks, Zr 3d$_{5/2}$, and Zr 3d$_{3/2}$, and the positions of these two peaks are separated by about 2.32 eV. The Zr 3d$_{5/2}$ could be assigned to two sub-peaks: ZrB$_2$ (178.6 eV) and ZrO$_2$ (183.3 eV); whereas the Zr 3d$_{3/2}$ is composed of another two sub-peaks: ZrB$_2$ (180.9 eV) and ZrO$_2$ (186.6 eV) [30,31]. Based on previous studies, the binding energy values of B$_{1s}$ in Figure 4b correspond to the ZrB$_2$ compounds and simple substance B, and the boron oxides is not observed to correspond to higher binding energy (193.3 eV) [30]. It can be seen that the 3d$_{5/2}$ and 3d$_{3/2}$ sub-peaks of ZrB$_2$ are much wider and more intensive than that of ZrO$_2$ in Figure 4a. Thus, Zr and B atoms mainly exist in the Zr-B bond in the composite films.
The composite films prepared by adding soft phase, ZrO$_2$, have the orientation of (001) plane of ZrB$_2$, which helps the film maintain a high hardness and avoid being too brittle. Besides, when increasing the sputtering power of ZrB$_2$ target, the deposition rate of ZrB$_2$ was accelerated by the higher sputtering power of ZrB$_2$ target. However, the elastic modulus of composite films basically maintains invariable or even decreases, exhibiting the opposite trend to that of hardness. The maximum hardness value of Zr-B-O nanocomposite films reaches 26.76 GPa when the sputtering power of ZrB$_2$ target decreases, exhibiting the opposite trend to that of hardness. The maximum hardness value of Zr-B-O nanocomposite films increases with the increasing sputtering power of the ZrB$_2$ target. However, the elastic modulus of composite films basically maintains invariable or even decreases, exhibiting the opposite trend to that of hardness. The maximum hardness value of Zr-B-O nanocomposite films reaches 26.76 GPa when the sputtering power of ZrB$_2$ target is 120 W and its corresponding elastic modulus is 268.05 Gpa, which are much higher than ZrB$_2$ and ZrO$_2$ monolayer films. This is because ZrB$_2$, with its hexagonal crystal structure, exhibits highly anisotropic properties. The hardness of (001) plane of ZrB$_2$ is much higher than that of (100) plane [33]. The composite films prepared by adding soft phase, ZrO$_2$, have the orientation of (001) plane of ZrB$_2$, which helps the film maintain a high hardness and avoid being too brittle. Besides, when increasing the sputtering power of ZrB$_2$ target, the deposition rate of ZrB$_2$ was accelerated by the higher sputtering energy. Therefore, the relative content of ZrB$_2$ increased, which shortened the distance of ZrB$_2$ sub-grains and increased the size of crystallization of ZrB$_2$ grains.

Figure 6 exhibits indentation morphology and the critical fracture load of ZrB$_2$ monolayer and Zr-B-O nanocomposite films. Nano scratch tests were performed on the samples surface with a linearly increased load. In these tests, the maximum load was set to 5 N. These films scratches were observed by feedback of friction signal. The load corresponding to an abrupt increase in the friction signal is the critical fracture load ($L_c$) of the sample. Therefore, critical fracture load can indirectly characterize the adhesion capacity or fracture resistance of film. Beyond that, other factors such as hardness, plastic recovery, and internal stress also affect the fracture resistance of films. For the ZrB$_2$ monolayer shown in Figure 6, when the load of indenter rises to 2.58 N at 1.03 mm, the friction curve appears to steeply
increase, indicating that the film starts to fall off the substrate. Similarly, the critical fracture loads of the Zr-B-O composite film with 80 and 120 W power of ZrB$_2$ target are 2.83 and 2.98 N respectively under the same test conditions. They are all higher than that of the ZrB$_2$ monolayer. The working mode of magnetron sputtering produced good adhesion of film to substrate. Further, the atomic mixture between the film adding ZrO$_2$ and Si (100) substrate is more favorable to promote the critical fracture load. The composite film prepared by 120 W power of ZrB$_2$ has higher critical load because of its higher content of ZrB$_2$ hard phase. According to the surface morphology of each sample and the friction value at the beginning of the scratch test, the composite film surface can be very smooth and flat by controlling the magnetron sputtering method under appropriate parameters. Almost no defects were observed on the surface. Such a dense surface is more conducive to resist outside damage and peel off from substrate.

![Graph](image.png)

**Figure 5.** Hardness and elastic modulus of ZrB$_2$, ZrO$_2$ monolayers, and Zr-B-O nanocomposite films at different sputtering powers of the ZrB$_2$ target.

![Graph](image.png)

**Figure 6.** Indentation morphology and critical fracture load of ZrB$_2$ monolayer and Zr-B-O nanocomposite films (80 and 120 W power of ZrB$_2$ target).
3.2. Oxidation Resistance Properties

In order to observe the oxidation of thin films at different temperatures with different sputtering powers, many attempts have been made. It is found that the mass loss of composite films below 650 °C can be influenced by the evaporation of water vapor and impurities on film surfaces. Hence the observation of oxidation resistance of the samples was chosen at a temperature range of 650 to 950 °C. Figure 7a shows the fitting curves of oxidation-mass change of Zr-B-O composite films (different power of ZrB$_2$) annealed from 650 to 950 °C for 1 h. Clearly, the mass of all samples increased from 650 °C. At the same testing temperature, the greater the sputtering power, the greater the mass change. On the other side, the films quality changes more with the rise of temperature. As can be seen from the diagram, the Zr-B-O nanocomposite films which were sputtered at 120 W of ZrB$_2$ target are more stable with oxidation temperature rising. By observing samples’ surfaces, the films become loose from 850 °C. In general, the mass changes of nanocomposite films before and after heat treatment are about 0.1% and all the nanocomposite films do not fall off obviously from the silicon wafer. Different from nanocomposite films, the ZrB$_2$ monolayer film at 80 W sputtering power appears to be partially detached after 850 °C oxidation. The addition of ZrO$_2$ as a soft phase can effectively reduce the oxidation-mass gain. From earlier research [34], ZrB$_2$ can be oxidized to form a layer of vitreous material containing B$_2$O$_3$ under 1100 °C and then hinder further oxidation. It can be concluded that the Zr-B ionic bonds are broken at high temperature, and the external O atoms penetrate into the film and form ZrO$_2$ with Zr atoms, while the B atoms transform to B$_2$O$_3$. The specific oxidation reaction is as follows:

$$\text{ZrB}_2 + \frac{5}{2}\text{O}_2 \rightarrow \text{ZrO}_2 + \text{B}_2\text{O}_3 (1)$$

Figure 7. Fitting curves of (a) oxidation-mass change and (b) XRD patterns of Zr-B-O nanocomposite films (120 W power of ZrB$_2$ target) at different testing temperatures.

That is the reason why the nanocomposite films have mass gain at high temperature. Next, the addition of ZrO$_2$ in ZrB$_2$ could well control the size of grain in the films. The dense structure of amorphous inside the composite films has fewer defects, which can be conducive to preventing the invasion of oxygen atoms on the whole. For another, the composite film with 80 W power of ZrB$_2$ has more mass change perhaps because of the higher relative content of ZrO$_2$. The original O atoms in the film are mixed into the sub-crystal structure of ZrB$_2$, which is easier to destroy the original structure in the oxidation process.

The XRD patterns of Zr-B-O composite films (120 W power of ZrB$_2$ target) annealed from 650 to 950 °C for 1 h are given in Figure 7b. Starting from 750 °C, the internal transition of the film is from amorphous to crystalline. ZrB$_2$ is in a completely amorphous state which the (001) and (101) crystal orientation are inhibited as temperature rises. Besides, the appearance of m-ZrO$_2$ (−111), m-ZrO$_2$ (200), and m-ZrO$_2$ (111) crystal plane indicates that the growth of low temperature monoclinic phase of ZrO$_2$...
is promoted. Furthermore, three diffraction peaks of high-temperature tetragonal phase of ZrO\(_2\) are identified from 750 to 950 °C, corresponding to (011), (112), and (121) planes, respectively. The mixed texture of two phases in the films from 750 °C is consistent with references [35,36]. The stable and dense oxide layer formed after oxidation is also detected as B\(_2\)O\(_3\), preventing O atoms from further entering under 1000 °C. On the other hand, the grains’ growth and phase transition will bring about a certain amount of volume change, leading to nanocomposite films fracture at the critical point of 1000 °C and peeling off from the substrates.

By observing the oxidation of the surface of films under different temperatures, the film at 120 W sputtering power of ZrB\(_2\) target after 850 °C oxidation was selected to study the microstructure changes of Zr-B-O nanocomposite film because it began to fall off after oxidation. As we can see in Figure 8a, the blurred selected area electron diffraction (SAED) patterns along with the amorphous-featured halo indicate poor crystallinity of the composite film. Two bright rings and a diffuse halo ring correspond to ZrB\(_2\) (101), m-ZrO\(_2\) (111), and ZrB\(_2\) (001). Figure 8b shows the TEM diffraction pattern of the sample at low magnification. It is obvious that the microstructure of Zr-B-O film is characterized as a nanocomposite structure with ZrO\(_2\) in the dark contrast surrounded by ZrB\(_2\) in the bright contrast. Due to the thick amorphous interface, the whole film has a dense structure. Even though the oxide layer is constantly inwardly expanding, the amorphous effect is that it absorbs more energy and there is a crystal transition process that dissipates a lot of heat. The grain size does not change too much in a short time.

![Figure 8](image-url)

**Figure 8.** (a) SAED patterns and (b) TEM image of Zr-B-O nanocomposite film at 120 W sputtering power of the ZrB\(_2\) target, and (c) SAED patterns and (d) elemental mapping image of Zr-B-O nanocomposite film at 120 W sputtering power of ZrB\(_2\) target after 850 °C oxidation for 1 h.

After high-temperature oxidation, the typical polycrystalline structure of the film is shown in Figure 8c. The sharp diffraction rings can be assigned to m-ZrO\(_2\) (−111), m-ZrO\(_2\) (111), m-ZrO\(_2\) (200), and t-ZrO\(_2\) (112). These crystallites exhibit various growth orientations, perhaps because the ZrB\(_2\) has completely turned into amorphous interfacial phase. The thick amorphous interface could not coordinate the misorientations between the ZrO\(_2\) crystallites, which led to the random growth orientations of the ZrO\(_2\) crystallites [37,38]. What’s more, it can be observed from elemental mapping in Figure 8d that most of the color represented by oxygen element is concentrated in the top layer of
the film. The deeper the film is, the lighter the film is oxidized. It is further proved that the dense amorphous structure effectively prevents the further oxidation of outside oxygen atoms.

3.3. Corrosion Resistance Properties

Figure 9 depicts the potentiodynamic polarization curves of the Zr-B-O nanocomposite films in 3.5 wt.% NaCl solution. For comparison, the stainless-steel substrate and ZrB\(_2\) monolayer were also tested. Meanwhile, the corrosion current densities (\(i_{\text{corr}}\)) obtained by fitting polarization curves in Figure 9 are listed in Table 1. The data clearly reveals that after the addition of ZrO\(_2\), the \(i_{\text{corr}}\) decreases by one order of magnitude from 2.9057 \(\times\) 10\(^{-6}\) A·cm\(^{-2}\) of stainless-steel substrate to 4.5310 \(\times\) 10\(^{-7}\) A·cm\(^{-2}\) of the Zr-B-O nanocomposite film with 80 W sputtering power of ZrB\(_2\) target. This indicates that the composite films doped with ZrO\(_2\) could greatly improve the corrosion resistance of the substrate as a whole. In combination with Figure 9, the \(i_{\text{corr}}\) of the polarization curves gradually decreases with the reduction of sputtering power of ZrB\(_2\), indicating that the corrosion resistance of Zr-B-O nanocomposite films are slightly strengthened with the increased the power of ZrB\(_2\). It can also be seen from the polarization curves that the films surfaces are smooth and compact, because ZrO\(_2\) has changed the crystal structure of the ZrB\(_2\) monolayer after mixing. The corrosion resistance of amorphous composite films is effectively improved by reason that there are no defects such as grain boundary [39,40]. These conclusions will be further confirmed by the following EIS analysis.

![Figure 9. Potentiodynamic polarization curves of the stainless-steel substrate, ZrB\(_2\) monolayer and Zr-B-O nanocomposite films in 3.5 wt.% NaCl solution.](image)

<table>
<thead>
<tr>
<th>Samples</th>
<th>Untreated</th>
<th>ZrB(_2)</th>
<th>Zr-B-O (80 W)</th>
<th>Zr-B-O (100 W)</th>
<th>Zr-B-O (120 W)</th>
</tr>
</thead>
<tbody>
<tr>
<td>(i_{\text{corr}}) (A·cm(^{-2}))</td>
<td>2.9057 (\times) 10(^{-6})</td>
<td>2.8869 (\times) 10(^{-6})</td>
<td>4.5310 (\times) 10(^{-7})</td>
<td>4.7362 (\times) 10(^{-7})</td>
<td>4.9919 (\times) 10(^{-7})</td>
</tr>
</tbody>
</table>

Figure 10 displays the Nyquist and Bode plots of the stainless-steel substrate, ZrB\(_2\) monolayer, and Zr-B-O nanocomposite films. The diameter of the capacitive loop of Nyquist plot and the impedance value of Bode plot are related to the corrosion resistance. The Nyquist plots in Figure 10a have similar shapes to each other. Furthermore, the capacitive loops diameter of Zr-B-O nanocomposite films is much larger than that of the stainless-steel substrate and ZrB\(_2\) monolayer. On the other hand, the impedance values of composite films increase with the reduction of sputtering power of ZrB\(_2\) target from the Bode plot in Figure 10b. This indicates that the amorphous composite films have improved the corrosion resistance of the substrate and the ZrB\(_2\) monolayer to some extent. The lower deposition power with lower bombarding energy leads to the deepening of the amorphous degree of composite
films, making the composite film with 80 W sputtering power of ZrB$_2$ have better corrosion resistance. The EIS results are consistent with polarization curves in explaining the corrosion behavior of Zr-B-O nanocomposite films.

![Figure 10. Electrochemical impedance spectroscopy (EIS) plots of the stainless-steel substrate, ZrB$_2$ monolayer and Zr-B-O nanocomposite films. (a) Nyquist plot. (b) Bode plot.](image)

By comparing the relationship between the above mechanical properties, oxidation resistance and corrosion resistance and combining with its structural characteristics, it is not difficult to find that such a dense amorphous structure is conducive to preventing external damage. At the low power of ZrB$_2$, the severe amorphous structure of the thin film is conducive to improving its corrosion resistance. When the power of ZrB$_2$ increases, the mechanical properties are promoted by increasing the relative content of ZrB$_2$, and the oxidation resistance is enhanced by trace amounts of oxygen atoms and compact oxidation film. The amorphous structure and internal oxygen content of the films have a direct effect on these properties.

4. Conclusions

A method of mixing ZrO$_2$ was designed to improve the oxidation and corrosion resistance of Zr-B-O nanocomposite films while maintaining the good mechanical properties of ZrB$_2$. In the process of simultaneous deposition of ZrB$_2$ and ZrO$_2$ to form nanocomposite films, the crystallinity of composite films is poor due to their mutual inhibition during sputtering. The Zr-B-O nanocomposite films have high microhardness because there is still a preferred orientation of ZrB$_2$ (001) plane in the composite films. When the power of ZrB$_2$ target increased to 120 W, the hardness of the composite film reached up to 26.76 GPa and the corresponding elastic modulus decreased to 268.05 GPa due to the addition of ZrO$_2$. Meanwhile, the maximum critical fracture load was up to 2.98 N. Due to the most heat absorbed by the amorphous part and lower oxygen content inside, the oxidation-mass change of the composite film with 120 W power of ZrB$_2$ varied by only 0.1% under 1000 °C for 1 h. Conversely, the corrosion resistance of Zr-B-O nanocomposite films was negatively correlated with the sputtering power of ZrB$_2$ target. The improved corrosion resistance was exhibited by the film with a denser amorphous structure at 80 W sputtering power of ZrB$_2$. Thus, there is a direct correlation between mechanical properties, oxidation resistance, and corrosion resistance due to the microstructure and oxygen content of films. The power of ZrB$_2$ will find an equilibrium value between 80 and 120 W in these properties.

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